

Features

- Meets MIL-S-19500/323
- Collector-Base Voltage 60V
- Collector Current: 200 mA
- Fast Switching 370 nS

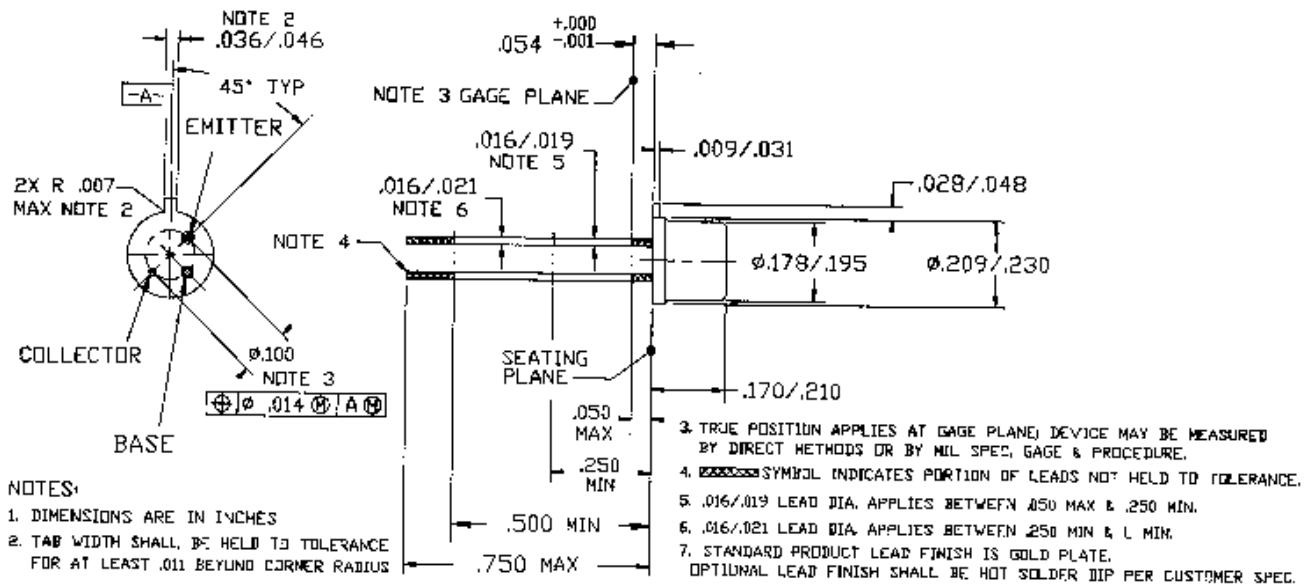
**60 Volts
 200 mAmps**

**PNP
 BIPOLEAR
 TRANSISTOR**

Maximum Ratings

RATING	SYMBOL	MAX.	UNIT
Collector-Emitter Voltage	V_{CEO}	-60	Vdc
Collector-Base Voltage	V_{CBO}	-60	Vdc
Emitter-Base Voltage	V_{EBO}	-5.0	Vdc
Collector Current	I_C	-200	mAdc
Total Device Dissipation $\text{@ } T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	0.36 2.4	Watts $\text{mW}/^\circ\text{C}$
Total Device Dissipation $\text{@ } T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	1.2 8	Watts $\text{mW}/^\circ\text{C}$
Operating Temperature Range	T_J	-65 to +175	$^\circ\text{C}$
Storage Temperature Range	T_S	-65 to +175	$^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Case	$R_{\theta JC}$	146	$^\circ\text{C}/\text{W}$

Mechanical Outline



Electrical Parameters ($T_A @ 25^\circ C$ unless otherwise specified)

CHARACTERISTICS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Off Characteristics					
Collector-Emitter Breakdown Voltage(1) ($I_C = -10 \text{ mA}$)	BV_{CEO}	-60		--	Vdc
Collector-Base Breakdown Voltage ($I_C = -10 \mu\text{A}$)	BV_{CBO}	-60		--	Vdc
Emitter-Base Breakdown Voltage ($I_E = -10 \mu\text{A}$)	BV_{EBO}	-5.0		--	Vdc
Collector Cutoff Current ($V_{CE} = -40 \text{ Vdc}$, $V_{EB} = -3.0 \text{ Vdc}$ (at 150°C))	I_{CEX}	--		-20 -20	nA uA
Base Cutoff Current ($V_{CE} = -40 \text{ Vdc}$, $V_{EB} = -3.0 \text{ Vdc}$)	I_{BEX}	--		-50	nAdc
D.C. Current Gain ($I_C = -0.1 \text{ mA}$, $V_{CE} = -1.0 \text{ Vdc}$) ($I_C = -1.0 \text{ mA}$, $V_{CE} = -1.0 \text{ Vdc}$) ($I_C = -1.0 \text{ mA}$, $V_{CE} = -1.0 \text{ Vdc}$) @ -55°C ($I_C = -10 \text{ mA}$, $V_{CE} = -1.0 \text{ Vdc}$)(1) ($I_C = -50 \text{ mA}$, $V_{CE} = -1.0 \text{ Vdc}$)(1)	h_{FE}	80 90 40 100 30		-- -- -- 300 --	--
Collector-Emitter Saturation Voltage(1) ($I_C = -10 \text{ mA}$, $I_B = -1.0 \text{ mA}$) ($I_C = -50 \text{ mA}$, $I_B = -5.0 \text{ mA}$)	$V_{CE(Sat)}$	-- --		-0.25 -0.5	Vdc
Base-Emitter Saturation Voltage(1) ($I_C = -10 \text{ mA}$, $I_B = -1.0 \text{ mA}$) ($I_C = -50 \text{ mA}$, $I_B = -5.0 \text{ mA}$)	$V_{BE(Sat)}$	-0.6 --		-0.9 -1.2	Vdc
Magnitude of common emitter small-signal short-circuit forward current transfer ratio ($I_C = -10 \text{ mA}$, $V_{CE} = -20 \text{ Vdc}$, $f = 100\text{MHz}$)	$/h_{fe}/$	3.0		9.0	
Output Capacitance ($V_{CB} = -10 \text{ Vdc}$, $I_E = 0$, $100\text{kHz} \leq f \leq 1\text{MHz}$)	C_{OBO}	--		6.0	pf
Input Capacitance ($V_{EB} = -10 \text{ Vdc}$, $I_C = 0$, $100\text{kHz} \leq f \leq 1\text{MHz}$)	C_{IBO}	--		8.0	pf
Input Impedance ($I_C = -1.0 \text{ mA}$, $V_{CE} = -10 \text{ V}$, $f = 1.0 \text{ kHz}$)	h_{ie}	2.0		12	kohms
Voltage Feedback Ratio ($I_C = -1.0 \text{ mA}$, $V_{CE} = -10 \text{ V}$, $f = 1.0 \text{ kHz}$)	h_{re}	--		20	$\times 10^{-4}$
Small-Signal Current Gain ($I_C = -1.0 \text{ mA}$, $V_{CE} = -10 \text{ V}$, $f = 1.0 \text{ kHz}$)	h_{fe}	100		400	--
Output Admittance ($I_C = -1.0 \text{ mA}$, $V_{CE} = -10 \text{ V}$, $f = 1.0 \text{ kHz}$)	h_{oe}	10		60	μmhos
Collector Base Time Constant ($I_C = -10 \text{ mA}$, $V_{CE} = -20 \text{ V}$, $f = 31.8 \text{ MHz}$)	$r_b' C_C$	5		250	ps
Noise Figure ($I_C = -100 \mu\text{A}$, $V_{CE} = -5.0 \text{ V}$, $R_S = 1.0\text{k}\Omega$, $f = 100 \text{ Hz}$)	NF	--		6.0	dB
Switching Speeds ($V_{CC} = -3.0 \text{ Vdc}$, $V_{BE} = +0.5 \text{ Vdc}$ $I_C = -10 \text{ mA}$, $I_{B1} = -1.0 \text{ mA}$) ($V_{CC} = -10 \text{ mA}$, $I_{B1} = I_{B1} = -1.0 \text{ mA}$) ($V_{CC} = -3.0 \text{ V}$)	t_{on} t_{off}	-- -- --		70 300	ns ns

(1) Pulse Test: PW = 300 μs , Duty Cycle = 2.0%